

**Micro Commercial Components** 

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# 2SD880

# **Features**

- With TO-220 package
- Power amplifier applications
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0

# **Maximum Ratings**

Symbol	Rating	Rating	Unit
$V_{CEO}$	Collector-Emitter Voltage	60	V
$V_{CBO}$	Collector-Base Voltage	60	V
V <sub>EBO</sub>	Emitter-Base Voltage	7	V
Ic	Collector Current	3	A
Pc	Collector power dissipation	1.5	W
TJ	Junction Temperature	-55 to +150	$^{\circ}$
$T_{STG}$	Storage Temperature	-55 to +150	$^{\circ}\mathbb{C}$

## Electrical Characteristics @ 25°C Unless Otherwise Specified

Symbol	Parameter	Min	Type	Max	Units	
OFF CHARACTERISTICS						
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage (I <sub>C</sub> =50mAdc, I <sub>B</sub> =0)	60			Vdc	
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage (I <sub>c</sub> =100uAdc, I <sub>E</sub> =0)	60			Vdc	
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage (I <sub>E</sub> =100uAdc, I <sub>C</sub> =0)	7			Vdc	
I <sub>CBO</sub>	Collector-Base Cutoff Current $(V_{CB}=60Vdc,I_{E}=0)$			100	uAdc	
I <sub>EBO</sub>	Emitter-Base Cutoff Current (V <sub>ER</sub> =7Vdc, I <sub>C</sub> =0)			100	uAdc	

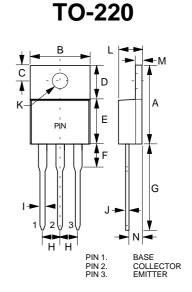
#### ON CHARACTERISTICS

h <sub>FE</sub>	Forward Curre (I <sub>C</sub> =500mAdd	60		300		
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage (I <sub>C</sub> =3Adc, I <sub>B</sub> =300mAdc)				1	Vdc
$V_{BE}$	Base-Emitter Voltage (I <sub>C</sub> =0.5Adc,V <sub>CE</sub> =5Vdc)				1	Vdc
f⊤	Transistor Frequency (I <sub>C</sub> =500mAdc, V <sub>CE</sub> =5Vdc)			3		MHz
C <sub>ob</sub>	Collector Output Capacitance $(V_{CB}=10Vdc, I_E=0, f=1MHz)$			70		pF
t <sub>on</sub>	Turn on time			0.8		us
ts	Storage time	I <sub>B1</sub> =-I <sub>B2</sub> =0.2A, I <sub>C</sub> =2A, V <sub>CC</sub> =30V. PW=20us		1.5		us
t <sub>f</sub>	Fall time	vcc=30 v, P vv=20us		0.8		us

### **Classification OF herro**

Rank	Q	Υ	GR
Range	60-120	100-200	150-300

# NPN Silicon Power Transistors



DIMENSIONS							
	INCHES		MM				
DIM	MIN	MAX	MIN	MAX	NOTE		
Α	.560	.625	14.22	15.88			
В	.380	.420	9.65	10.67			
С	.100	.135	2.54	3.43			
D	.230	.270	5.84	6.86			
Е	.380	.420	9.65	10.67			
F		.250		6.35			
G	.500	.580	12.70	14.73			
Н	.090	.110	2.29	2.79			
- 1	.020	.045	0.51	1.14			
J	.012	.025	0.30	0.64			
K	.139	.161	3.53	4.09	Ø		
L	.140	.190	3.56	4.83			
M	.045	.055	1.14	1.40			
N	.080	.115	2.03	2.92			

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